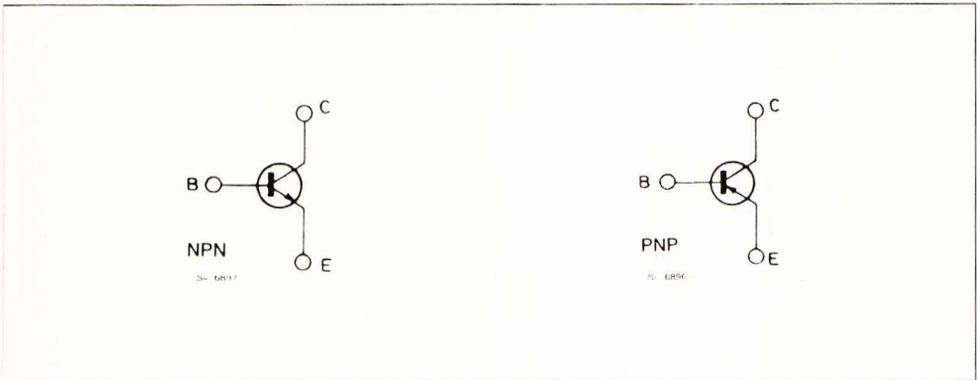


AUDIO AMPLIFIER
DESCRIPTION

The BC286 is a silicon planar epitaxial NPN transistor in Jedec TO-39 metal case. It is mainly intended for use as audio amplifier.

The complementary PNP type is the BC287.


INTERNAL SCHEMATIC DIAGRAM

ABSOLUTE MAXIMUM RATINGS

| Symbol | Parameter | Value | Unit |
|----------------|---|-------------|------------------|
| V_{CBO} | Collector-base Voltage ($I_E = 0$) | 70 | V |
| V_{CEO} | Collector-emitter Voltage ($I_B = 0$) | 60 | V |
| V_{EBO} | Emitter-base Voltage ($I_C = 0$) | 5 | V |
| I_C | Collector Current | 1 | A |
| P_{tot} | Total Power Dissipation at $T_{amb} \leq 25^\circ\text{C}$ at $T_{case} \leq 25^\circ\text{C}$ | 0.75 | W |
| | | 4 | W |
| T_{stg}, T_J | Storage and Junction Temperature | - 55 to 175 | $^\circ\text{C}$ |

THERMAL DATA

| | | | | |
|------------------|-------------------------------------|-----|-----|---------------|
| $R_{th\ j-case}$ | Thermal Resistance Junction-case | Max | 37 | $^{\circ}C/W$ |
| $R_{th\ j-amb}$ | Thermal Resistance Junction-ambient | Max | 200 | $^{\circ}C/W$ |

ELECTRICAL CHARACTERISTICS ($T_{amb} = 25\ ^{\circ}C$ unless otherwise specified)

| Symbol | Parameter | Test Conditions | Min. | Typ. | Max. | Unit |
|-----------------|--|--|------|------------|------|--------|
| I_{CBO} | Collector Cutoff Current ($I_E = 0$) | $V_{CB} = 30\ V$ | | | 20 | nA |
| $V_{(BR)CBO}$ | Collector-base Breakdown Voltage ($I_E = 0$) | $I_C = 100\ \mu A$ | 70 | | | V |
| $V_{(BR)CEO}^*$ | Collector-emitter Breakdown Voltage ($I_B = 0$) | $I_C = 30\ mA$ | 60 | | | V |
| $V_{(BR)EBO}$ | Collector-emitter Breakdown Voltage ($I_C = 0$) | $I_E = 100\ \mu A$ | 5 | | | V |
| $V_{CE(sat)}^*$ | Collector-emitter Saturation Voltage | $I_C = 500\ mA$ $I_B = 50\ mA$ $I_C = 1\ A$ $I_B = 0.1\ A$ | | 0.4 0.7 | 1 | V V |
| V_{BE}^* | Base-emitter Voltage | $I_C = 500\ mA$ $V_{CE} = 2\ V$ | | 1 | | V |
| h_{FE}^* | DC Current Gain | $I_C = 100\ mA$ $V_{CE} = 2\ V$ $I_C = 500\ mA$ $V_{CE} = 2\ V$ | 20 | 90 60 | | |
| f_T | Transition Frequency | $I_C = 50\ mA$ $V_{CE} = 5\ V$ $f = 100\ MHz$ | | 100 | | MHz |
| C_{CBO} | Collector-base Capacitance | $I_E = 0$ $V_{CB} = 10\ V$ $f = 1\ MHz$ | | 12 | | pF |

* Pulsed : pulse duration = 300 ms, duty cycle = 1 %.